DMC204A0

Silicon NPN epitaxial planar type

For low frequency amplification

■ Features

- ullet Low collector-emitter saturation voltage $V_{CE(sat)}$
- Halogen-free / RoHS compliant
 (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

■ Marking Symbol: C1

■ Basic Part Number

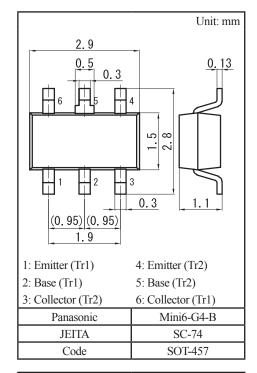
Dual DSC2501 (Individual)

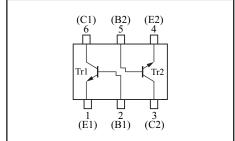
Packaging

DMC204A00R Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

■ Absolute Maximum Ratings $T_a = 25$ °C

	Parameter	Symbol	Rating	Unit	
Tr1 Tr2	Collector-base voltage (Emitter open)	V _{CBO}	25	V	
	Collector-emitter voltage (Base open)	V _{CEO}	20	V	
	Emitter-base voltage (Collector open)	V _{EBO}	12	V	
	Collector current	I_{C}	0.5	A	
	Peak collector current	I _{CP}	1	A	
Overall	Total power dissipation	P _T	300	mW	
	Junction temperature	T_j	150	°C	
	Operating ambient temperature	T _{opr}	-40 to +85	°C	
	Storage temperature	T _{stg}	-55 to +150	°C	



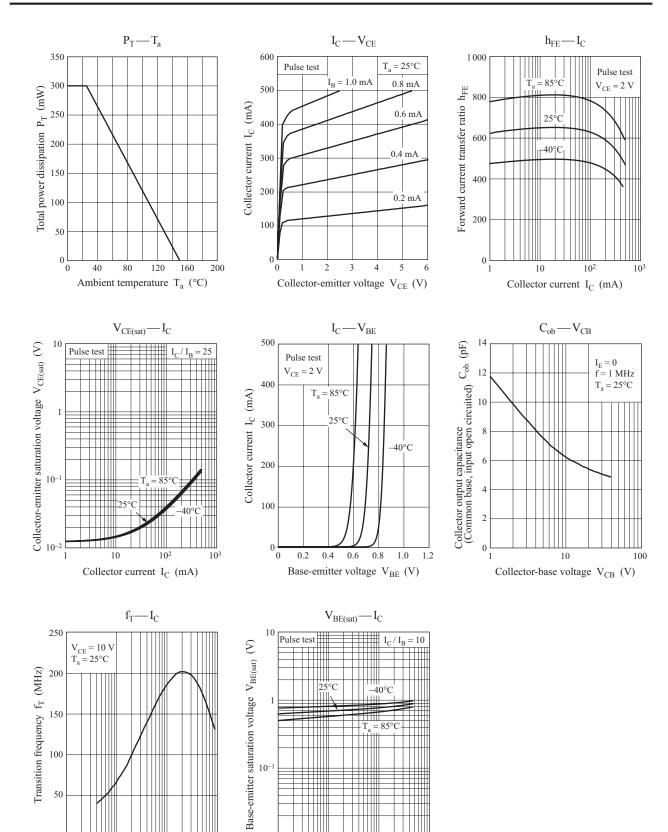


■ Electrical Characteristics $T_a = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu A, I_{\rm E} = 0$	25			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	20			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10 \mu A, I_C = 0$	12			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 25 \text{ V}, I_{E} = 0$			100	nA
Forward current transfer ratio	h _{FE}	$V_{CE} = 2 \text{ V}, I_{C} = 0.5 \text{ A}$	200		800	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm C} = 0.5 \text{A}, I_{\rm B} = 20 \text{mA}$		0.18	0.40	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_{\rm C} = 0.5 \text{A}, I_{\rm B} = 50 \text{mA}$			1.2	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 50 \text{ mA}$		150		MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		6		pF
(Common base, input open circuited)	Cob	VCB 10 V, IE 0,1 I WIIIZ		3		Pi
ON resistance	R _{on}			1.0		Ω

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement



 10^{-2}

10

Collector current I_C (mA)

 10^{2}

 10^{3}

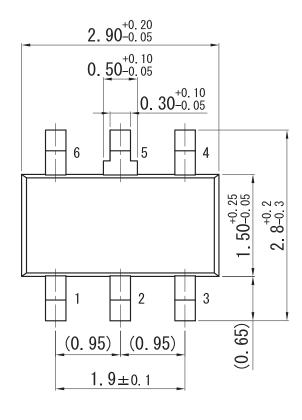
100

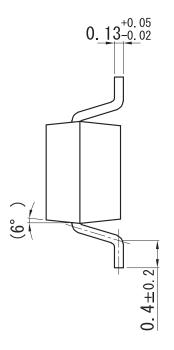
Collector current I_C (mA)

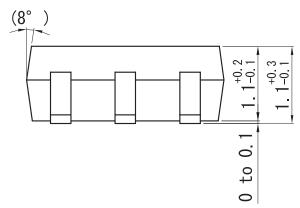
Ver. CED 2

Mini6-G4-B

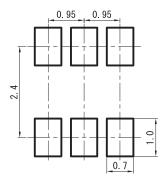
Unit: mm







■ Land Pattern (Reference) (Unit: mm)



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